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FDS8842NZ N-Channel PowerTrench[®] MOSFET

40 V, 14.9 A, 7.0 mΩ

Features

- Max $r_{DS(on)}$ = 7.0 m Ω at V_{GS} = 10 V, I_D = 14.9 A
- Max $r_{DS(on)}$ = 11.6 m Ω at V_{GS} = 4.5 V, I_D = 11.6 A
- HBM ESD protection level of 4.4 kV typical(note 3)
- High performance trench technology for extremely low r_{DS(on)} and fast switching
- High power and current handling capability
- Termination is Lead-free and RoHS Compliant

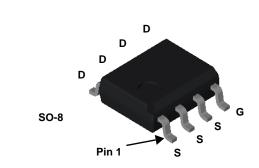


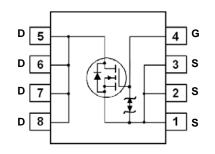
General Description

The FDS8842NZ has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest $r_{DS(on)}$ while maintaining excellent switching performance.

Applications

- Synchronous Buck for Notebook Vcore and Server
- Notebook Battery
- Load Switch





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			40	V	
V _{GS}	Gate to Source Voltage		±20	V		
ID	Drain Current -Continuous			14.9	^	
	-Pulsed			93	Α	
E _{AS}	Single Pulse Avalanche Energy		(Note 4)	253	mJ	
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	W	
	Power Dissipation	T _A = 25 °C	(Note 1b)	1.0	VV	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/W

Package Marking and Ordering Information

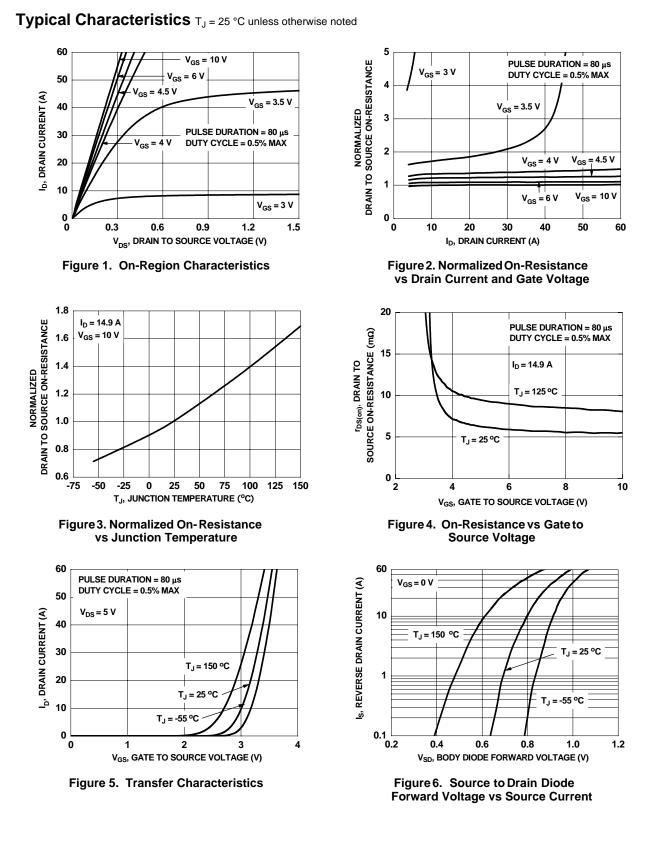
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8842NZ	FDS8842NZ	SO8	13 "	12 mm	2500 units

February 2009

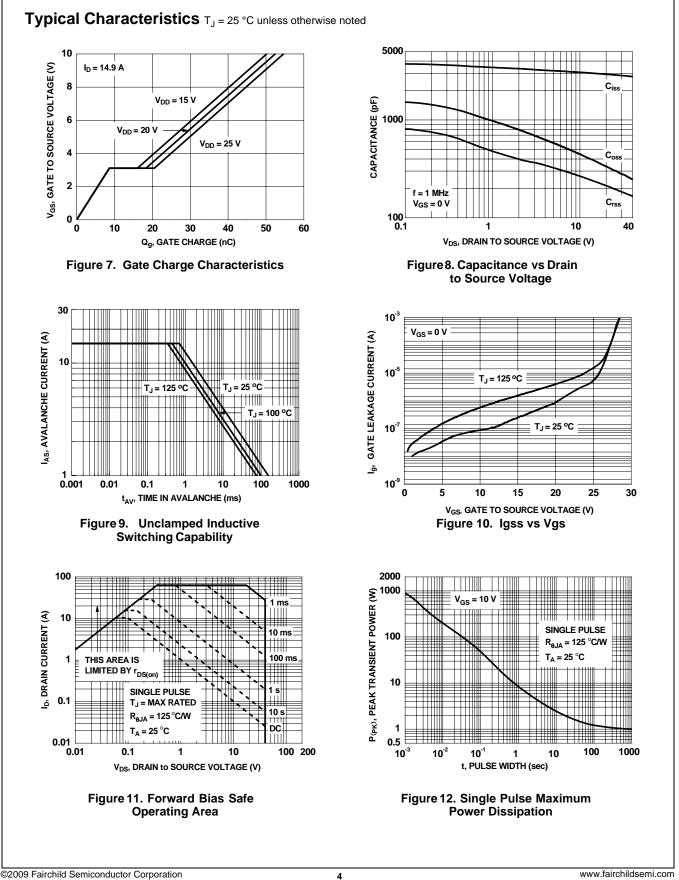
Off Charact	Parameter	Test Conditions	Min	Тур	Max	Units
	eristics				·	
BV _{DSS} [Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	40			V
ΔBV_{DSS} E	Breakdown Voltage Temperature	$I_D = 250 \ \mu$ A, referenced to 25 °C		35		mV/°C
I _{DSS} Z	Zero Gate Voltage Drain Current	V _{DS} = 32 V, V _{GS} = 0 V			1	μΑ
	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
On Charact	eristics				-	-i
	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.0	1.9	3.0	V
	Gate to Source Threshold Voltage					
<u> </u>	Temperature Coefficient	$I_D = 250 \ \mu A$, referenced to 25 °C		-6		mV/°C
		V _{GS} = 10 V, I _D = 14.9 A		5.6	7.0	
r _{DS(on)} Static Drain to Source Or	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 11.6 \text{ A}$		6.7	11.6	mΩ
		V_{GS} = 10 V, I _D = 14.9 A, T _J =125 °C		8.9	11.1	
g _{FS} F	Forward Transconductance	V _{DS} = 5 V, I _D = 14.9 A		111		S
Dvnamic Cl	haracteristics					
-	nput Capacitance			2890	3845	pF
	Dutput Capacitance	$V_{\rm DS} = 15 \rm V, V_{\rm GS} = 0 \rm V,$		340	455	pF
	Reverse Transfer Capacitance	f = 1 MHz		220	330	pF
	Gate Resistance	f = 1 MHz		0.8		Ω.
	Characteristics			I	1	1
	Furn-On Delay Time			13	23	ns
÷(•··)	Rise Time	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 14.9 \text{ A},$ $V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		7	14	ns
1	Furn-Off Delay Time			34	54	ns
÷(•)	Fall Time			5	10	ns
1	Fotal Gate Charge	V _{GS} = 0 V to 10 V		52	73	nC
3	Total Gate Charge	$V_{DD} = 0 V to 5 V$ $V_{DD} = 20 V$,		27	38	nC
· ·	Gate to Source Charge	$I_{\rm D} = 14.9 \rm{A}$		8.6		nC
9-	Gate to Drain "Miller" Charge			9.7		nC
3 -				0.1		
Drain-Sour	ce Diode Characteristics	$V_{0}V_{1400}$		0.0	10	
V _{SD} S	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 14.9 A$ $V_{GS} = 0 V, I_S = 2.1 A$		0.8 0.7	1.2 1.2	V
+ [Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = 2.1 A$		26	42	ns
	Reverse Recovery Charge	– I _F = 14.9 A, di/dt = 100 A/μs		15	27	nC
NOTES:	Reverse Recovery Charge			15	21	ne

2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%. 3. The diode connected between the gate and source servers only as protection against ESD. No gate overvoltage rating is implied. 4. Starting T_J = 25 °C, L = 3 mH, I_{AS} = 13 A, V_{DD} = 40 V, V_{GS} = 10 V.

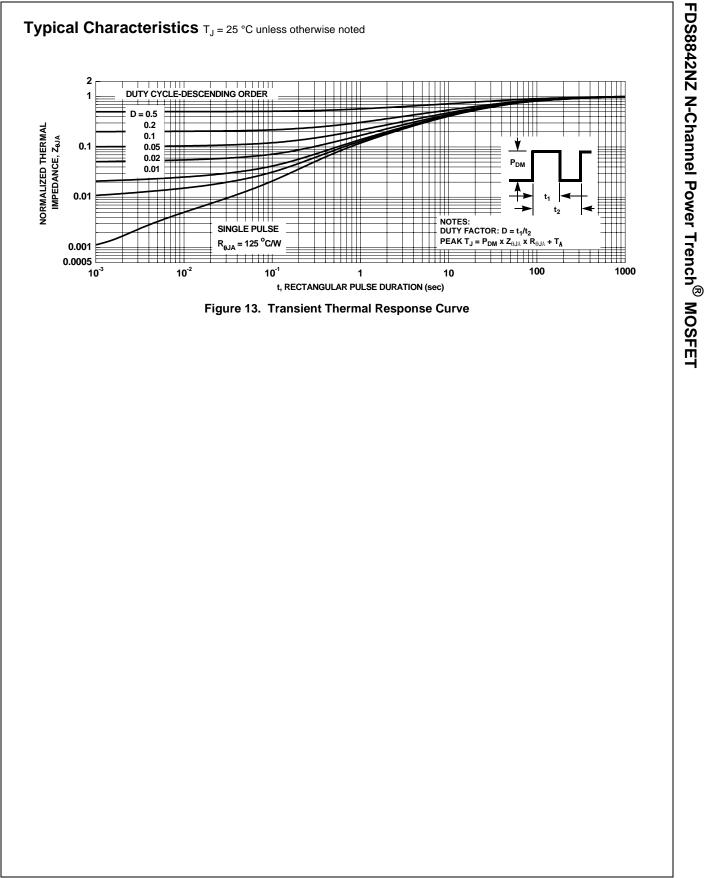
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The Power Franchise[®]

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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